

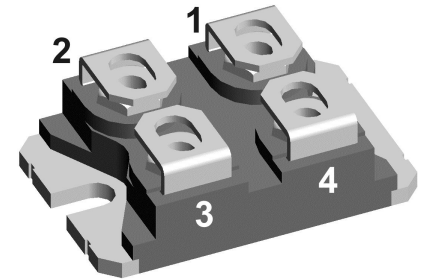
# Standard Rectifier

1~ Rectifier	
$V_{RRM}$	= 800 V
$I_{DAV}$	= 40 A
$I_{FSM}$	= 320 A

## 1~ Rectifier Bridge

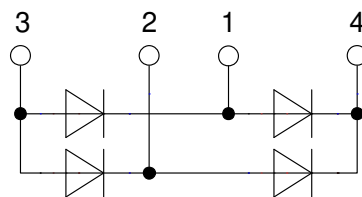
Part number

**VBO40-08NO6**



Backside: isolated

 E72873



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

### Disclaimer Notice

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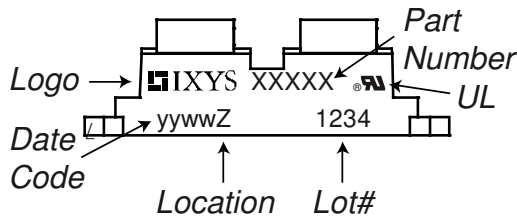


Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					900	V
$V_{RRM}$	max. repetitive reverse blocking voltage					800	V
$I_R$	reverse current	$V_R = 800\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		40	$\mu\text{A}$
		$V_R = 800\text{ V}$		$T_{VJ} = 150^\circ\text{C}$		1.5	mA
$V_F$	forward voltage drop	$I_F = 20\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		1.15	V
		$I_F = 40\text{ A}$				1.33	V
		$I_F = 20\text{ A}$		$T_{VJ} = 125^\circ\text{C}$		1.07	V
		$I_F = 40\text{ A}$				1.31	V
$I_{DAV}$	bridge output current	$T_C = 115^\circ\text{C}$		$T_{VJ} = 150^\circ\text{C}$		40	A
		rectangular	d = 0.5				
$V_{F0}$	threshold voltage			$T_{VJ} = 150^\circ\text{C}$		0.81	V
$r_F$	slope resistance					12.1	m $\Omega$
		} for power loss calculation only					
$R_{thJC}$	thermal resistance junction to case					1.3	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.1		K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		95	W
$I_{FSM}$	max. forward surge current	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		320	A
		t = 8,3 ms; (60 Hz), sine		$V_R = 0\text{ V}$		345	A
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		270	A
		t = 8,3 ms; (60 Hz), sine		$V_R = 0\text{ V}$		295	A
$I^2t$	value for fusing	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		510	A <sup>2</sup> s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0\text{ V}$		495	A <sup>2</sup> s
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		365	A <sup>2</sup> s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0\text{ V}$		360	A <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		11	pF



Package SOT-227B (minibloc)				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$I_{RMS}$	RMS current	per terminal			150	A	
$T_{VJ}$	virtual junction temperature		-40		150	°C	
$T_{op}$	operation temperature		-40		125	°C	
$T_{stg}$	storage temperature		-40		150	°C	
<b>Weight</b>					30	g	
$M_D$	mounting torque		1.1		1.5	Nm	
$M_T$	terminal torque		1.1		1.5	Nm	
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	10.5	3.2		mm	
$d_{Spb/Apb}$		terminal to backside	8.6	6.8		mm	
$V_{ISOL}$	isolation voltage	t = 1 second		3000		V	
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	2500		V	

**Product Marking**



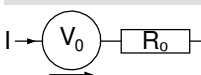
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VBO40-08NO6	VBO40-08NO6	Tube	10	475866

Similar Part	Package	Voltage class
VBO40-12NO6	SOT-227B (minibloc)	1200
VBO40-16NO6	SOT-227B (minibloc)	1600

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$

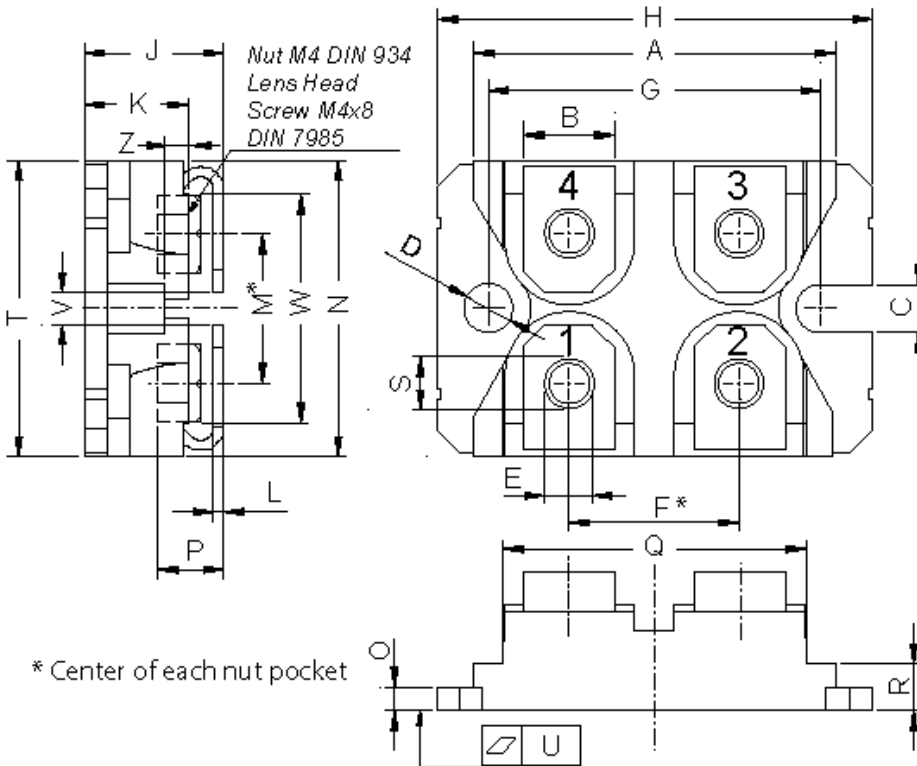


**Rectifier**

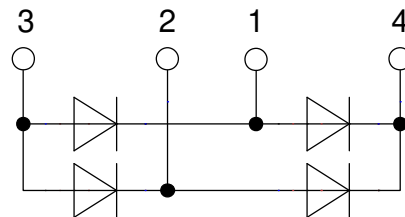
$V_{0\ max}$	threshold voltage	0.81	V
$R_{0\ max}$	slope resistance *	10.2	mΩ



**Outlines SOT-227B (minibloc)**



Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106





**Rectifier**

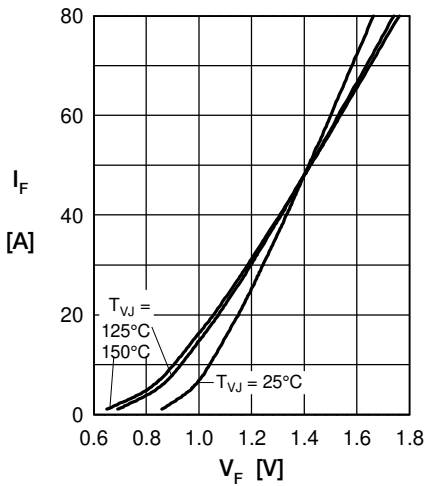


Fig. 1 Forward current vs. voltage drop per diode

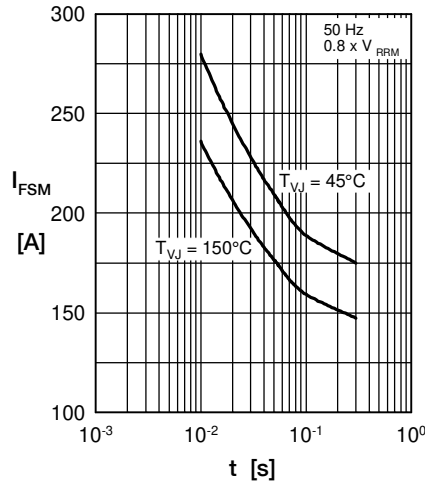


Fig. 2 Surge overload current vs. time per diode

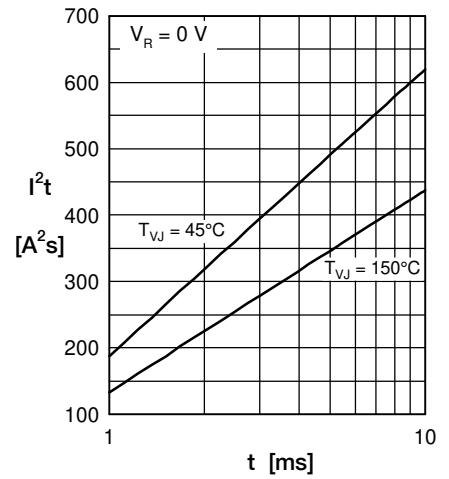


Fig. 3  $I^2t$  vs. time per diode

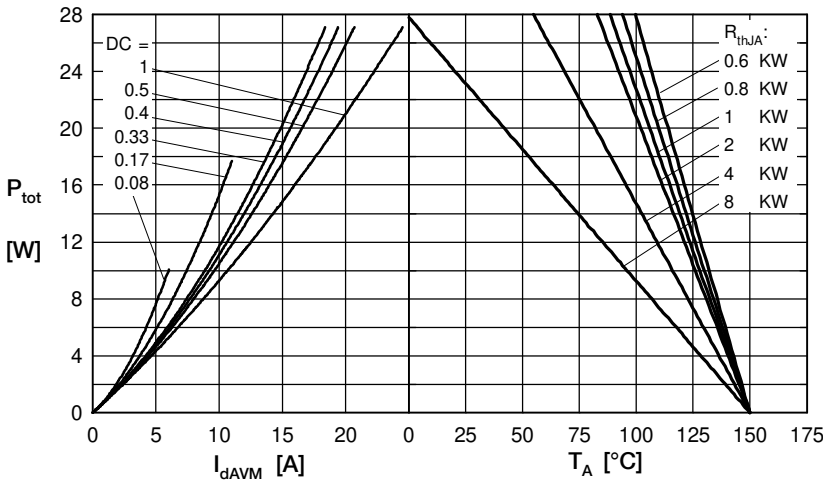


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

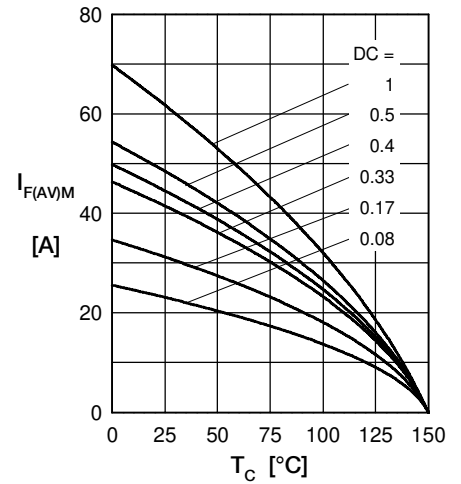


Fig. 5 Max. forward current vs. case temperature per diode

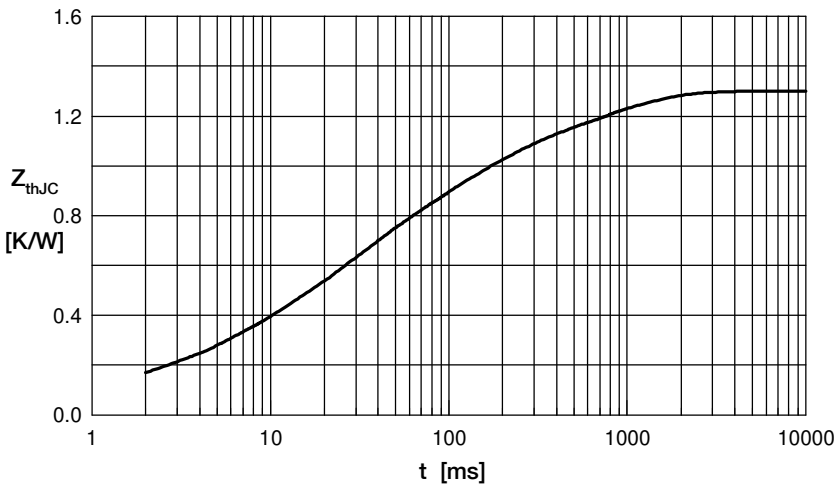


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

i	$R_{th}$ (K/W)	$t_i$ (s)
1	0.061	0.0002
2	0.145	0.0036
3	0.398	0.0200
4	0.405	0.1000
5	0.291	0.7000